



Attempt all questions, full mark: 40 Points

Time: 3 Hours

Question #1: (10 Points)

Choose the right answer:

- 1) If a sinusoidal voltage is applied to the base of a biased npn transistor and the resulting sinusoidal collector voltage is clipped near zero volts, the transistor is

A (A) being driven into saturation (B) being driven into cutoff
(C) operating nonlinearly

- 2) The input resistance of a common-base amplifier is

A (A) very low (B) very high
(C) the same as a CE (D) the same as a CC

- 3) The voltage gain of a common-base amplifier is

C (A) very low (B) very high
(C) the same as a CE (D) the same as a CC

- 4) The input resistance at the base of a biased transistor depends mainly on

D (A) β (B) R_E
(C) R_B (D) β and R_E

- 5) A differential amplifier

D (A) is used in op-amps (B) has one input and one output
(C) has two outputs (D) answers (A) and (C)

- 6) The maximum efficiency of a class A power amplifier is

A (A) 25% (B) 50%
(C) 75% (D) 78.5%

- 7) Crossover distortion is a problem for

C (A) class A amplifiers (B) class AB amplifiers
(C) class B amplifiers (D) all of these amplifiers

- 8) For $V_{GS} = 0$, the drain current in a JFET becomes constant when V_{DS} exceeds

C (A) cutoff (B) V_{DD}
(C) V_P (D) 0 V

- 9) A certain n-channel E-MOSFET has a $V_{GS(th)} = 2V$. If $V_{GS} = 0V$, the drain current is

A (A) 0 A (B) $I_{D(ON)}$
(C) maximum (D) I_{DSS}

- 10) Which of the following characteristics does not necessarily apply to an op-amp?

B (A) High gain (B) Low power
(C) High input impedance (D) Low output impedance

Question #2: (5 Points)

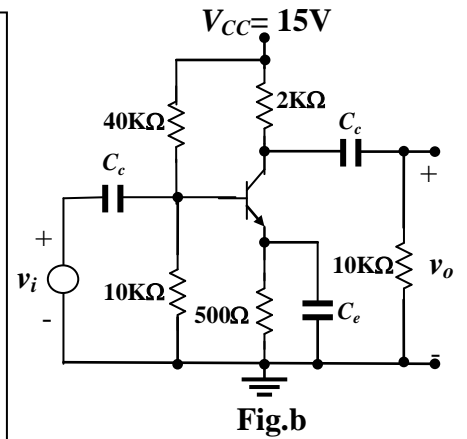
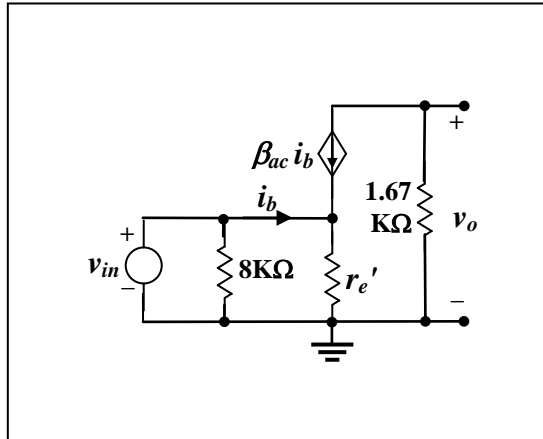
a) A certain transistor has $\alpha_{DC} = 0.99$. If the dc base current is $10 \mu\text{A}$, determine r_e' .

$$\beta = \alpha / (1 - \alpha) = 99$$

$$I_E = (\beta + 1)I_B = 1 \text{ mA}$$

$$r_e' = 25 / I_E = 25 \Omega$$

b) Draw the ac equivalent circuit for the amplifier in Fig.b



c) An n-channel JFET has $I_{DSS} = 5 \text{ mA}$ and $V_{GS(off)} = -8 \text{ V}$. What value of V_{GS} is required to set up a drain current of 2.25 mA .

$$I_D = 5[1 - V_{GS}/(-8)]^2 = 2.25$$

$$V_{GS} = -2.63 \text{ V}$$

d) A certain class A power amplifier has $V_{CEQ} = 12 \text{ V}$ and $I_{CQ} = 1 \text{ A}$. Find the maximum signal power output.

$$P_{out(max)} = V_{CEQ}I_{CQ}/2$$

$$= 6 \text{ W}$$

e) Find V_o in the circuit of Fig.(e).

$$V_o = -18 \text{ V}$$

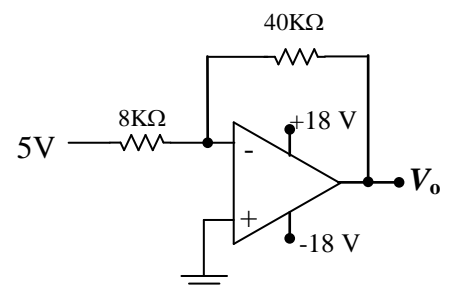


Fig.(e)

Question #3: (5 Points)

The silicon npn transistor used in the swamped amplifier shown in Fig.3 has $\beta_{dc} = \beta_{ac} = 100$.

- Find I_{CQ} and V_{CEQ} .
- Find r_e' .
- Find the voltage gain and input impedance of the amplifier.

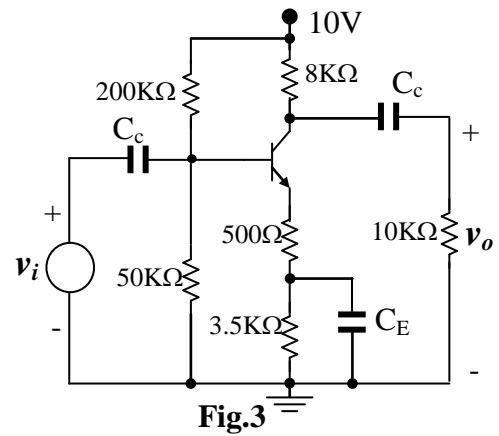


Fig.3

$I_{CQ} = 0.295 \text{ mA}$

$V_{CEQ} = 6.45 \text{ V}$

$r_e' = 84.6 \Omega$

$A_v = -7.6$

$Z_{in} = 23.75 \text{ K}\Omega$

Question #4: (5 Points)

A class-AB complementary-symmetry push-pull power amplifier is connected to a 6Ω load. The supply voltages are $\pm 24 \text{ V}$.

- Draw the amplifier circuit diagram. (1 Point)
- Find the peak value of the collector current, the DC power delivered by the source, and the amplifier efficiency if the ac power delivered to the load is 27 W . (3 Points)
- What would be the maximum allowable output power? (1 Point)

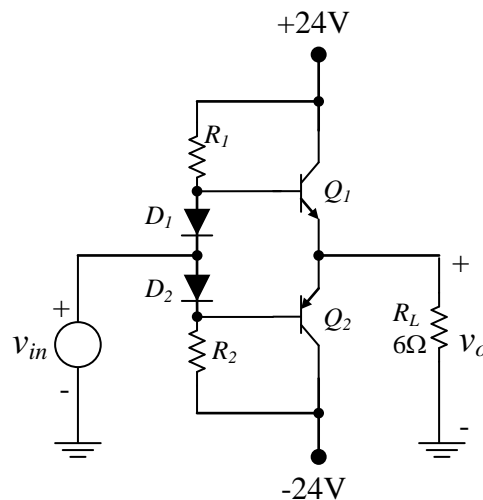
$I_{Cp} = 3 \text{ A}$

$P_{DC} = 45.83 \text{ W}$

Efficiency = 58.9%

$P_{out(max)} = 48 \text{ W}$

The Circuit Diagram



Question #5: (5 Points)

The JFET used in the common source amplifier of Fig.5 has $V_{GS(off)} = -5V$ and $I_{DSS} = 10\text{ mA}$.

- a) Determine the operating point I_{DQ} , V_{GSQ} and V_{DSQ} . (3 Points)
- b) Calculate the value of the transconductance g_m at the Q -point. (1 Point)
- c) Determine the amplifier voltage gain. (1 Point)

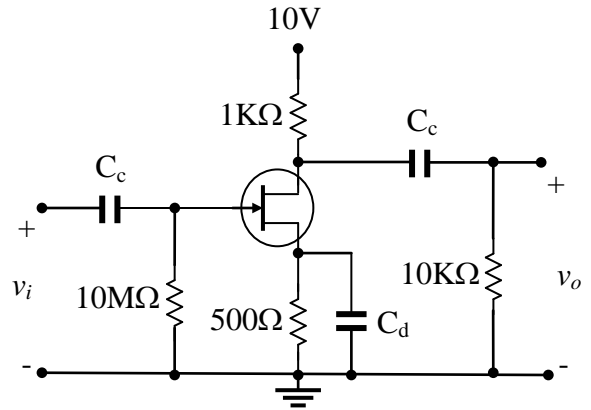


Fig.5

$I_{DQ} = 3.82\text{ mA}$

$V_{GSQ} = -1.91\text{ V}$

$V_{DSQ} = 4.27\text{ V}$

$g_m = 2.47\text{ mS}$

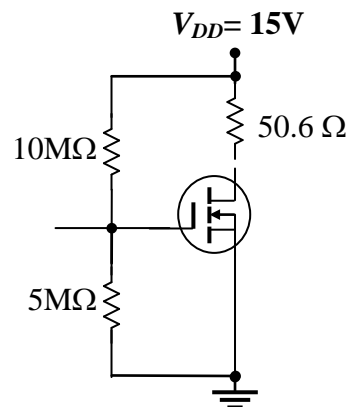
$A_v = -2.247$

Question #6: (3 Points)

- a) The data sheet for a 2N7008 E-MOSFET gives $I_{D(on)} = 500\text{ mA}$ at $V_{GS} = 10\text{ V}$ and $V_{GS(th)} = 1\text{ V}$. Determine the drain current for $V_{GS} = 5\text{ V}$. (1 Point)
- b) The transistor is to operate at: $V_{GSQ} = 5\text{ V}$, $V_{DSQ} = 10V$. Draw a suitable circuit to bias this transistor giving suitable resistances values, assuming that $V_{DD} = 15V$. (2 Points)

$I_D = 98.765\text{ mA}$

The Circuit Diagram



Question #7: (3 Points)

- a) Find the output voltage when the indicated input voltages are applied to the scaling adder of Fig.7. (2 Points)
- b) What is the value of the current through R_f ? (1 Point)

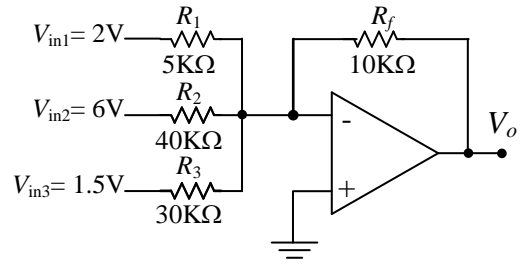


Fig.7

$V_o = -6 \text{ V}$

$I_f = 0.6 \text{ mA}$

Question #8: (4 Points)

The voltage waveform v_g shown in Fig.(8-a) is applied to the circuit of Fig.(8-b). Sketch v_o versus t , assuming ideal op-amp.

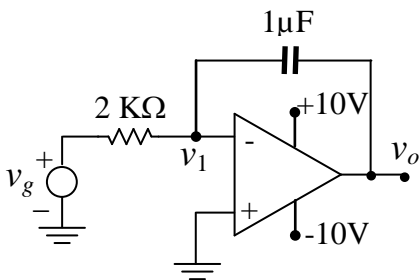


Fig. (8-b)

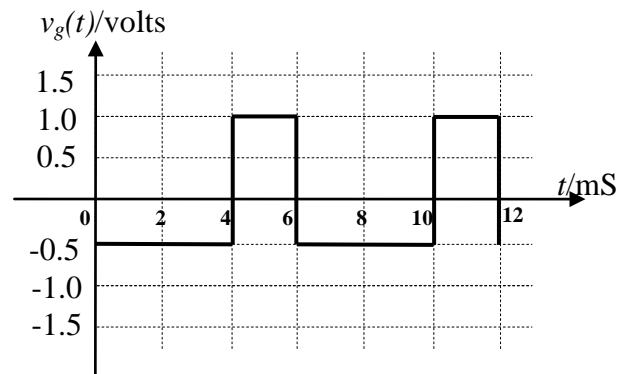


Fig. (8-a)

